AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application:

1. (Withdrawn) A method of manufacturing a semiconductor device, the method comprising:

preparing a first substrate including an integrated circuit chip, first connection terminals electrically connected to terminals of the integrated circuit chip, and a first connection portion spaced from the first connection terminals;

preparing a second substrate including second connection terminals to be electrically connected to the first connection terminals and a second connection portion spaced from the second connection terminals;

providing a metal material portion for bonding on the first connection portion or the second connection portion; and

stacking the first substrate and the second substrate by connecting the first connection portion and the second connection portion together via the metal material portion by thermo compression bonding.

2. (Withdrawn) The method of manufacturing a semiconductor device according to claim 1, further comprising stacking unit substrates each formed of the first and second substrates stacked.

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- 3. (Withdrawn) The method of manufacturing a semiconductor device according to claim 2, wherein stacking the unit substrates includes bonding the unit substrates adjacent to each other in a stacking direction using an adhesive sheet.
- 4. (Withdrawn) The method of manufacturing a semiconductor device according to claim 1, wherein the first connection portion is a first dummy terminal provided between the first connection terminals adjacent to each other in a plane direction, and the second connection portion is a second dummy terminal provided between the second connection terminals adjacent to each other in the plane direction.
- 5. (Withdrawn) The method of manufacturing a semiconductor device according to claim 1, wherein the first connection portion is a first dummy pad provided on the first substrate, and the second connection portion is a second dummy pad provided on the second substrate.
- 6. (Withdrawn) The method of manufacturing a semiconductor device according to claim 1, wherein the first connection portion is a first alignment mark provided on the first substrate and used to align the first substrate with the second substrate, and the second connection portion is a second alignment mark provided on the second substrate and used to align the first substrate with the second substrate.

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- 7. (Withdrawn) The method of manufacturing a semiconductor device according to claim 1, wherein the metal material portion is formed of solder, tin, or an Sn—Bi alloy.
- 8. (Withdrawn) The method of manufacturing a semiconductor device according to claim 3, wherein the adhesive sheet is formed of resin.
 - 9. (Currently amended) A semiconductor device comprising:

a first substrate including an integrated circuit chip, first connection terminals electrically connected to terminals of the integrated circuit chip, and a first connection portion spaced from the first connection terminals and not electrically connected to any terminal of the integrated circuit chip;

a second substrate stacked on the first substrate and including second connection terminals and a second connection portion spaced from the second connection terminals;-and

a metal material portion provided between the first connection portion and the second connection portion, bonding the first connection portion to the second connection portion and not electrically connected to any terminal of the integrated circuit chip, the first connection portion being bonded to the second connection portion by thermo compression bonding; and

the first connection terminals being electrically connected to the second connection terminals, the electrical connection between the first connection terminals

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and the second connection terminals not being provided by thermal compression

bonding.

10. (Original) The semiconductor device according to claim 9, wherein a

plurality of unit substrates are stacked, each of the unit substrates being formed of the

first and second substrates stacked.

11. (Original) The semiconductor device according to claim 10, further

comprising an adhesive sheet interposed between the unit substrates adjacent to each

other in a stacking direction and bonding the unit substrates together.

12. (Original) The semiconductor device according to claim 9, wherein the

first connection portion is a first dummy terminal provided between the first connection

terminals adjacent to each other in a plane direction, and the second connection portion

is a second dummy terminal provided between the second connection terminals

adjacent to each other in the plane direction.

13. (Original) The semiconductor device according to claim 9, wherein the

first connection portion is a first dummy pad provided on the first substrate, and the

second connection portion is a second dummy pad provided on the second substrate.

14. (Original) The semiconductor device according to claim 9, wherein the

first connection portion is a first alignment mark provided on the first substrate and used

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to align the first substrate with the second substrate, and the second connection portion

is a second alignment mark provided on the second substrate and used to align the first

substrate with the second substrate.

15. (Original) The semiconductor device according to claim 9, wherein the

metal material portion is formed of solder, tin, or an Sn—Bi alloy.

16. (Original) The semiconductor device according to claim 11, wherein the

adhesive sheet is formed of resin.

17. (Withdrawn) A method of manufacturing a semiconductor device, the

method comprising:

preparing a plurality of unit substrates each comprising a first substrate and a

second substrate stacked, the first substrate including an integrated circuit chip and first

connection terminals electrically connected to terminals of the integrated circuit chip, the

second substrate including second connection terminals electrically connected to the

first connection terminals; and

stacking the unit substrates by bonding the unit substrates adjacent to each other

in a stacking direction using an adhesive sheet.

18. (Withdrawn) The method of manufacturing a semiconductor device

according to claim 17, wherein the adhesive sheet is formed of resin.

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19-20. (Canceled)